TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MH161FK,TC7MH163FK

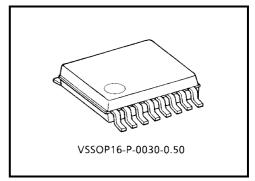
Synchronous Presettable 4-Bit Binary Counter TC7MH161FK Asynchronous Clear TC7MH163FK Synchronous Clear

The TC7MH161FK and 163FK are advanced high speed CMOS synchronous presettable 4-bit binary counters fabricated with silicon gate C^2 MOS technology.

They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

The CK input is active on the rising edge. Both \overline{LOAD} and \overline{CLR} inputs are active on low logic level.

Presetting of each IC's is synchronous to the rising edge of CK. The clear function of the TC7MH163FK is synchronous to CK, while the TC7MH161FK are cleared asynchronously.



Weight: 0.02 g (typ.)

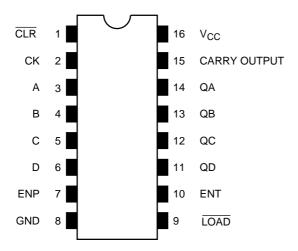
Two enable inputs (ENP and ENT) and CARRY OUTPUT are provided to enable easy cascading of counters, which facilitates easy implementation of n-bit counters without using external gates.

An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

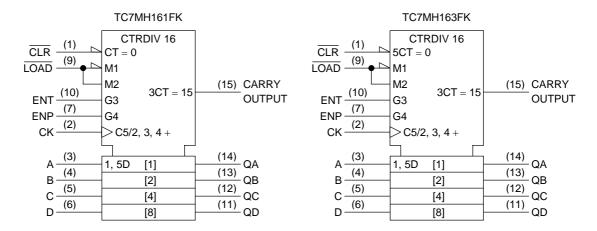
Features

- High speed: $f_{max} = 185 \text{ MHz (typ.)} (V_{CC} = 5 \text{ V})$
- Low power dissipation: $ICC = 4 \mu A \text{ (max) (Ta} = 25^{\circ}C)$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power down protection is equipped with all inputs.
- Balanced propagation delays: $t_pLH \approx t_pHL$
- Wide operating voltage range: $V_{CC (opr)} = 2 \sim 5.5 \text{ V}$
- Low noise: VOLP = 0.8 V (max)
- Pin and function compatible with 74ALS161/163

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

TC7MH161FK				TC7MH163FK				Outputs						
		Inputs			Inputs				Outputs				Function	
CLR	LD	ENP	ENT	СК	CLR	LD	ENP	ENT	СК	QA	QB	QC	QD	
L	Х	Х	Х	Χ	L	Х	Х	Х		L L L L			L	Reset to "0"
Н	L	Х	Х		Н	L	Х	Х	\triangle	Α	В	С	D	Reset data。
Н	Н	Х	L		Н	Н	Х	L	ightharpoonup	No change			No count	
Н	Н	L	Х		Н	Н	L	Х	ightharpoonup	No change				No count
Н	Н	Н	Н		Н	Н	Н	Н		Count up				Count
Н	Х	Х	Х		Х	Х	Х	Х	\neg	No change			No count	

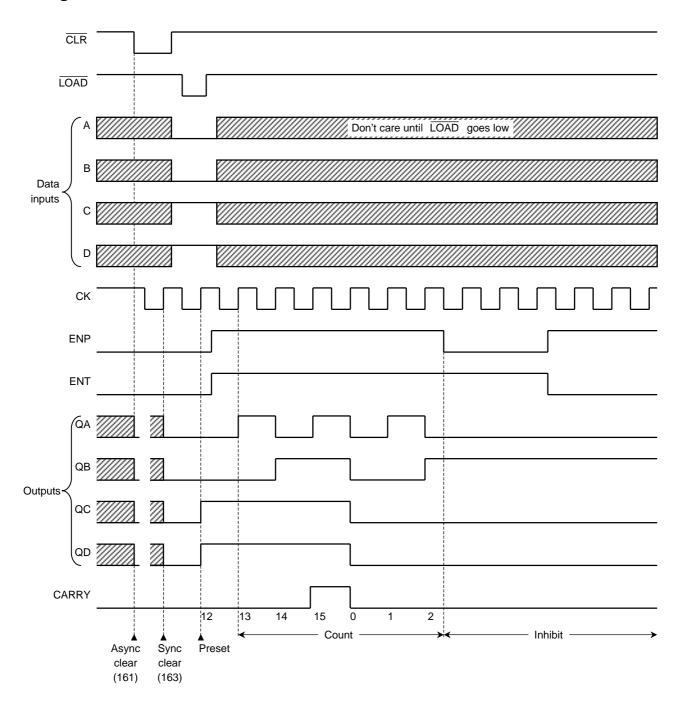
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X: Don't care

A, B, C, D: Logic level of data inputs

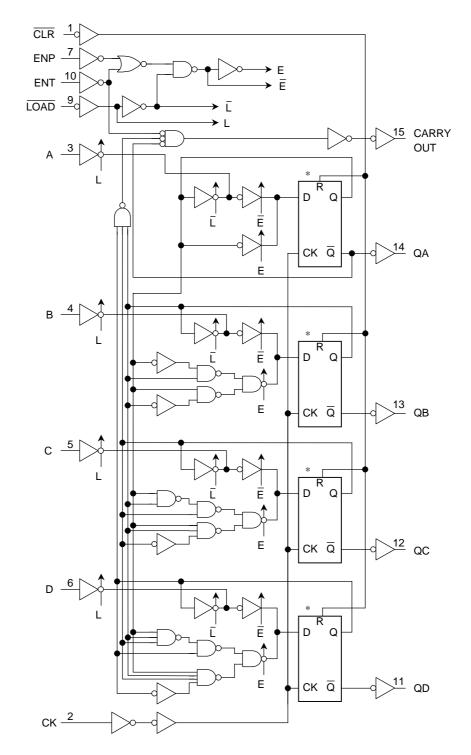
Carry: $CARRY = ENT \cdot QA \cdot QB \cdot QC \cdot QD$

Timing Chart



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System Diagram



*:Truth table of internal F/F

	TC	7MH16	1FK		TC7MH163FK						
D	CK	R	Q	IQ	D	CK	R	Q	Q		
Х	Х	Н	L	Н	Х	\Box	Н	L	Н		
L	ightharpoonup	L	L	Н	L	ightharpoonup	L	L	Н		
Н		L	Н	L	Н		L	Н	L		
Х	—	L	No change		Х	_	Х	No change			

X: Don't care



Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	I _{CC}	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	-65~150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0~5.5	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~V _{CC}	V	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	$0 \sim 100 \; (V_{CC} = 3.3 \pm 0.3 \; V)$	ns/V	
Input lise and fail tille	ui/uv	$0 \sim 20 \; (V_{CC} = 5 \pm 0.5 \; V)$	115/ V	

Electrical Characteristics

DC Characteristics

Characteristics		Symbol Test Condition			Ta = 25°C			Ta = -4	Unit									
Charac	tensucs			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit								
					2.0	1.50	_	_	1.50	_								
	_			V														
					2.0			0.50	_	0.50	V							
	Low level	V _{IL}		_	3.0~5.5	_	_	$\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$	_	$\begin{array}{c} V_{CC} \\ \times 0.3 \end{array}$								
		Voн	V _{IN} = V _{IH}		2.0	1.9	2.0	_	1.9	_								
				$I_{OH} = -50 \mu A$	3.0	2.9	3.0	_	2.9	_								
	High level				4.5	4.4	4.5	_	4.4	_								
												$I_{OH} = -4 \text{ mA}$	3.0	2.58	_	_	2.48	_
				$I_{OH} = -8 \text{ mA}$	4.5	3.94		_	3.80	_	V							
voltage					2.0		0	0.1	_	0.1	V							
				$I_{OL} = 50 \ \mu A$	3.0		0	0.1		0.1								
	Low level	V _{OL}	V _{IN} = V _{IH}		4.5		0	0.1		0.1								
				$I_{OL} = 4 \text{ mA}$	3.0			0.36		0.44								
				$I_{OL} = 8 \text{ mA}$	4.5		_	0.36		0.44								
Input leakage	current	I _{IN}	V _{IN} = 5.5 V or GND		0~5.5	_	_	±0.1	_	±1.0	μΑ							
Quiescent sup	ply current	Icc	$V_{IN} = V_{CC}$	or GND	5.5	_	_	4.0		40.0	μΑ							



Timing Requirements (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C	Ta = -40~85°C	Unit	
Characteristics	Symbol	rest Conditio	V _{CC} (V)	Limit Limit		Offic		
Minimum pulse width	t _{w (H)}	Figure 1		3.3 ± 0.3	5.0	5.0	ns	
(CK)	t _{w (L)}	rigule i		5.0 ± 0.5	5.0	5.0	115	
Minimum pulse width	+	Figure 4	(Note1)	3.3 ± 0.3	5.0	5.0	ns	
(CLR)	t _{w (L)}	Figure 4	(Note I)	5.0 ± 0.5	5.0	5.0		
Minimum set-up time	4	Figure 2		3.3 ± 0.3	5.5	6.5		
(A, B, C, D)	ts	Figure 2	5.0 ± 0.5	4.5	4.5	ns		
Minimum set-up time	4	Figure 2		3.3 ± 0.3	8.0	9.5	nc	
(LOAD)	ts	rigule 2		5.0 ± 0.5	5.0	6.0	ns	
Minimum set-up time	4	Figure 3		3.3 ± 0.3	7.5	9.0	20	
(ENT, ENP)	ts			5.0 ± 0.5	5.0	6.0	ns	
Minimum set-up time	4	Figure E	(Note 2)	3.3 ± 0.3	4.0	4.0		
(CLR)	ts	Figure 5	(Note2)	5.0 ± 0.5	3.5	3.5	ns	
Minimum hold time		Figure 2. Figure 2.		3.3 ± 0.3	1.0	1.0		
Minimum noid time	th	Figure 2, Figure 3	5.0 ± 0.5	1.0	1.0	ns		
Minimum hold time	4.	Figure F	(Note 2)	3.3 ± 0.3	1.0	1.0	20	
(CLR)	th	Figure 5	(Note2)	5.0 ± 0.5	1.5	1.5	ns	
Minimum removal time		Figure 4	(Natad)	3.3 ± 0.3	2.5	2.5	- ns	
(CLR)	t _{rem}	Figure 4	(Note1)	5.0 ± 0.5	1.5	1.5		

Note1: for TC7MH161FK only Note2: for TC7MH163FK only



AC Characteristics (Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition				Ta = 25°(Ta = -4	0~85°C	Unit
Characteristics	Symbol	rest Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Offic
			3.3 ± 0.3	15	_	8.3	12.8	1.0	1.0 18.5	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	3.3 ± 0.3	50	_	10.8	16.3	1.0	18.5	ns
(CK-Q)	t _{pHL}	rigule 1, rigule 2	5.0 ± 0.5	15	_	4.9	8.1	1.0	9.5	
			3.0 ± 0.3	50	_	6.4	10.1	1.0	11.5	
Propagation dolay time			3.3 ± 0.3	15		8.7	13.6	1.0	16.0	
Propagation delay time (CK-CARRY)	t _{pLH}	Figure 1	3.3 ± 0.3	50	_	11.2	17.1	1.0	19.5	ns
[Count mode]	t _{pHL}	i igure i	5.0 ± 0.5	15	_	4.9	8.1	1.0	9.5	115
[Count mode]			3.0 ± 0.3	50	_	6.4	10.1	1.0	11.5	
Dranagation daloy time			3.3 ± 0.3	15	_	11.0	17.2	1.0	20.0	
Propagation delay time (CK-CARRY)	t _{pLH}	Figure 2	3.3 ± 0.3	50	_	13.5	20.7	1.0	23.5	ns
[Preset mode]	t _{pHL}	Figure 2	5.0 ± 0.5	15	_	6.2	10.3	1.0	12.0	115
[Freder mode]			3.0 ± 0.3	50	_	7.7	12.3	1.0	14.0	
	t _{pLH} t _{pHL}		3.3 ± 0.3	15	_	7.5	12.3	1.0	14.5	ns .
Propagation delay time		Figure 6		50	_	10.5	15.8	1.0	18.0	
(ENT-CARRY)			5.0 ± 0.5	15	_	4.9	8.1	1.0	9.5	
			5.0 ± 0.5	50	_	6.4	10.1	1.0	11.5	
			22 02	15	_	8.9	13.6	1.0	16.0	
Propagation delay time	4	Figure 4 (Note 4)	3.3 ± 0.3	50	_	11.2	17.1	1.0	19.5	20
(CLR -Q)	t _{pHL}	Figure 4 (Note4)	5.0 ± 0.5	15	_	5.5	9.0	1.0	10.5	ns -
				50	_	7.0	11.0	1.0	12.5	
			3.3 ± 0.3	15	_	8.4	13.2	1.0	15.5	
Propagation delay time		Figure 4 (Note 4)	3.3 ± 0.3	50		10.9	16.7	1.0	19.0	
(CLR -CARRY)	t _{pHL}	Figure 4 (Note4)	50.05	15		5.0	8.6	1.0	10.0	ns
			5.0 ± 0.5	50	_	6.5	10.6	1.0	12.0	
			3.3 ± 0.3	15	80	130	_	70	_	
Maximum alaak fragusaasi			J.J ± U.J	50	55	85	_	50	_	
Maximum clock frequency	f _{max}	_	5.0 ± 0.5	15	135	185	_	115	_	MHz
			5.0 ± 0.5	50	95	125	_	85	_	
Input capacitance	C _{IN}	_			_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note3)	_	23		_		pF

Note3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

When the outputs drive a capacitive load, total current consumption is the sum of C_{PD} , and ΔI_{CC} which is obtained from the following formula:

$$\Delta I_{CC} = f_{CK} \cdot V_{CC} \left(\frac{C_{QA}}{2} + \frac{C_{QB}}{4} + \frac{C_{QC}}{8} + \frac{C_{QD}}{16} + \frac{C_{CO}}{16} \right)$$

 $C_{QA} \hbox{-} C_{QD}$ and C_{CO} are the capacitance QA-QD and CARRY OUT, respectively. f_{CK} is the input frequency of the CK.

Note4: for TC7MH161FK only

AC Test Waveform

Count Mode

CK t_{WH} t_{WL} t_{WL} t_{VCC} t_{DLH} t_{WH} t_{WL} t_{DLH} t_{DLH} t_{DLH} t_{DLH} t_{DLH} t_{DLH} t_{DLH} t_{DHL} t_{DHL

Figure 1

Preset Mode

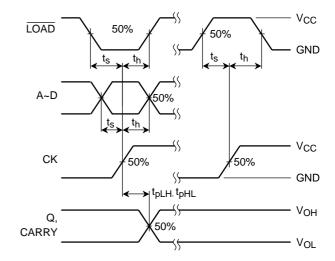
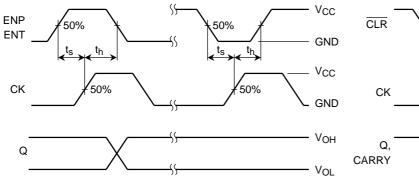


Figure 2

Count Enable Mode

Clear Mode (TC7MH161FK)



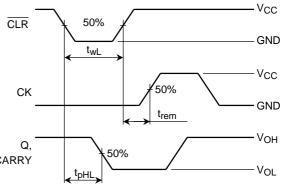


Figure 3 Figure 4

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Clear Mode (TC7MH163FK)

Figure 5

Cascade Mode (fix maximum count)

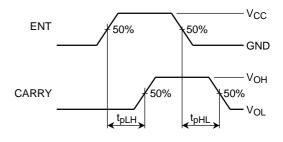
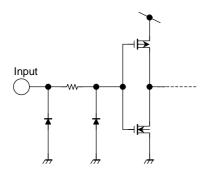


Figure 6

Noise Characteristics (Input: $t_r = t_f = 3$ ns)

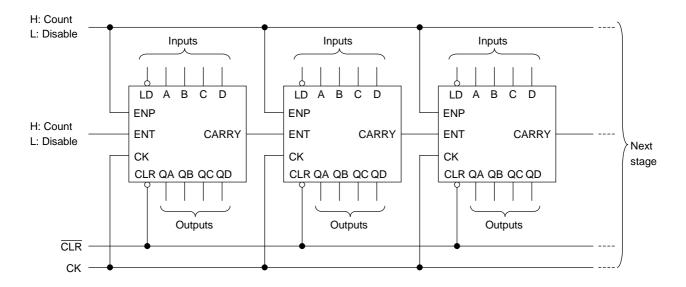
Characteristics	Symbol	Test Condition		Ta = 25°C		- Unit
Gridiacieristics	Symbol	rest Condition	V _{CC} (V)			
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.4	0.8	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.4	-0.8	V
Minimum high level dynamic input voltage V_{IH}	V _{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage $V_{\rm IL}$	V _{ILD}	C _L = 50 pF	5.0	_	1.5	V

Input Equivalent Circuit

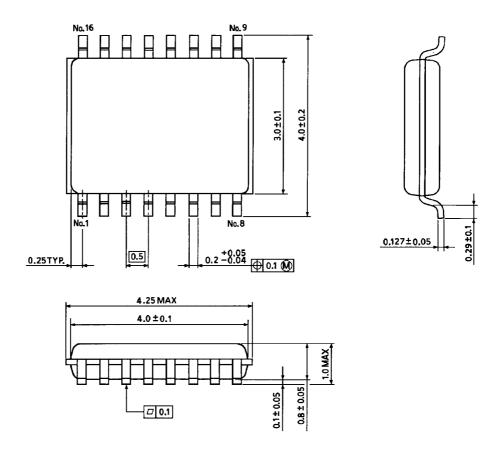


Typical Application

Parallel Carry N-Bit Counter



Package Dimensions



Weight: 0.02 g (typ.)

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000707EBA

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